Impedance Matching and Tuning

Matching networks are used to match the impedance of one system to another

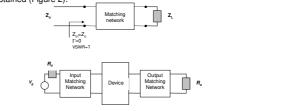
- Match is important for several reasons:
- Provides for maximum power transfer (e.g. carrying power from transmitter to an antenna).
- Improves the signal to noise ratio (e.g. when carrying input signals from an antenna to a receiver).
- Reduces amplitude and phase errors in power distribution networks (e.g. when designing a distribution network for an antenna array).
- Reduces the VSWR, increasing the maximum power-transfer ability of high-power transmission systems
- of nion-bower transmission systems E.g. if the input to a transistor at a particular frequency is taken to be $Z_L = 50 - j60$ and
- source applied to the input of the transistor has an output impedance of $Z_a=50$, we need to find a matching network such that $Z_{in}=Z_a^\ast$, or equivalently $Z_{out}=Z_L^\ast$

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•When a load connected to a line whose characteristic impedance differs from the load, there will be reflections resulting in a reduction in the power delivered to the load.

•To maximize the power delivered to the load, or equivalently reduce the reflection, a lossless impedance network should be inserted between the load and the line. This is called one-port impedance matching as depicted in Figure 1.

•For devices such as filters, amplifiers etc, both input matching and output matching are required to match the input and the output of the device so that maximum power should be delivered, correspondently low reflection is obtained (Figure 2).



What is a matching network?

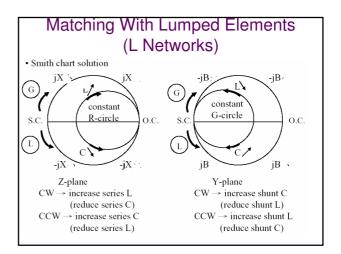
· Lumped and/or distributed elements

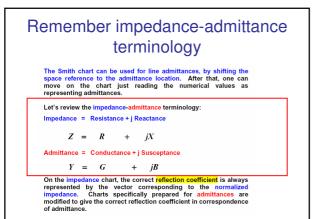
- Lumped elements
 - Consists of discrete components (resistors, inductors, capacitors, and possibly active devices)
 - Usually more compact
 - At high frequencies, parasitics reduce the effectiveness of the
 - components
 - Limited by practicality of components (e.g. can't have 1 mH inductor on monolithic circuit)

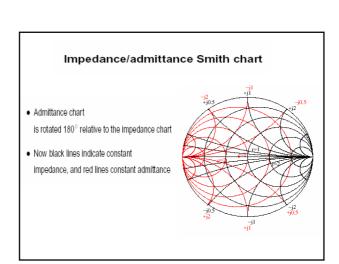
Distributed

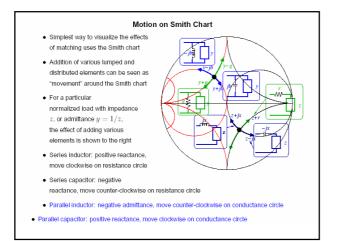
- Uses series transmission lines and stubs
- Take up much more space (which means larger cost for MMIC)
- Reactive parasitics associated with these usually much lower
- Ohmic losses may be significant due to their large size

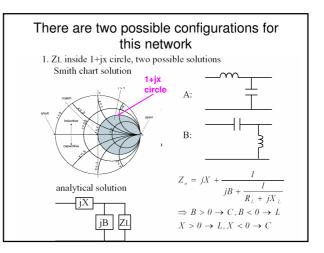
Both of these matching networks can be easily designed using - SMITH CHARTS!

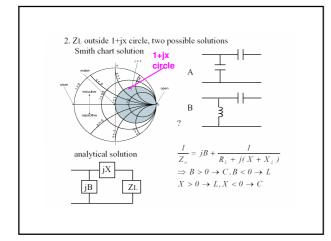


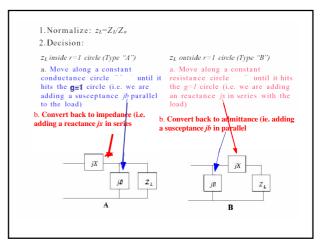


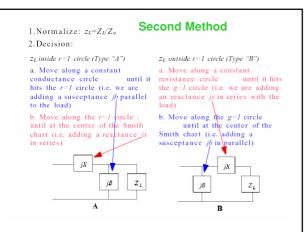


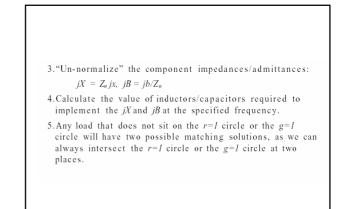






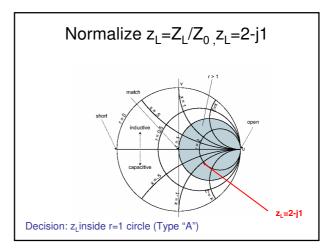


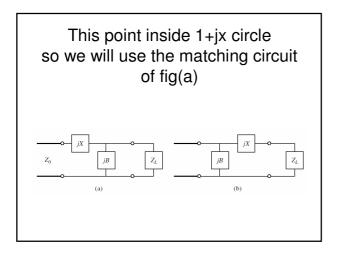


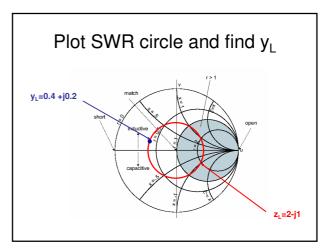


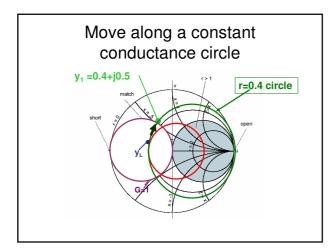
Example

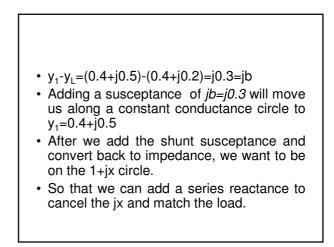
• Design an L-section matching network to match a series RC load with an impedance $Z_L=200$ -j100 Ω , to a 100 Ω line, at a frequency of 500 MHz.

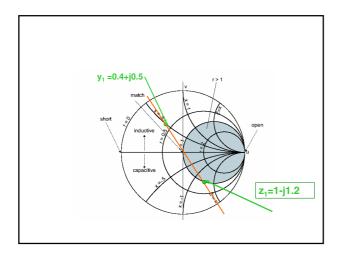


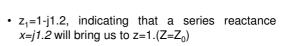




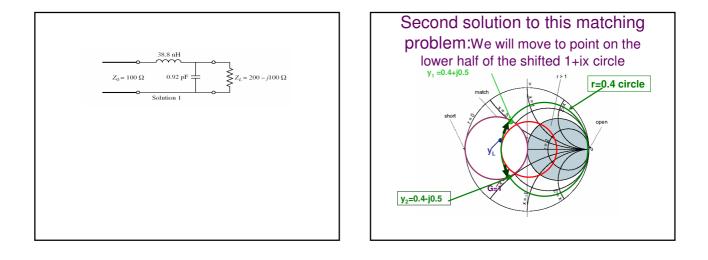


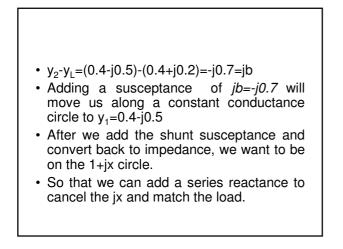


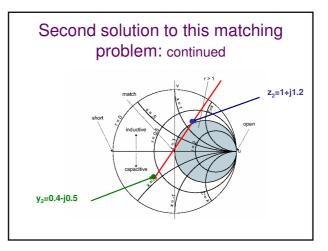


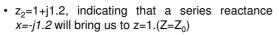


- This matching circuit consist of shunt capacitor (*b>0*) and a series inductor (*x>0*).
- shunt capacitor: *jB=jωC* and *B=b/Z₀* C=b/2πfZ₀=0.3/2π500×10⁶×100=0.92 pF
- Series inductor: $jX = j\omega L$ and $X = x.Z_0$ L=xZ₀/ 2 π f=38.8 nH



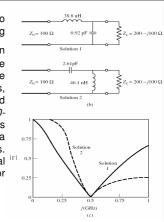


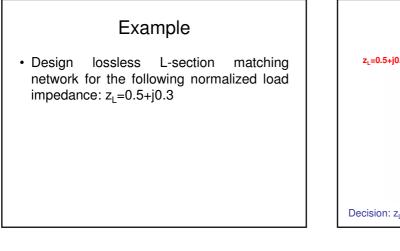


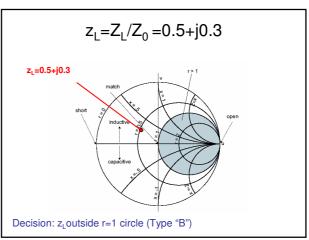


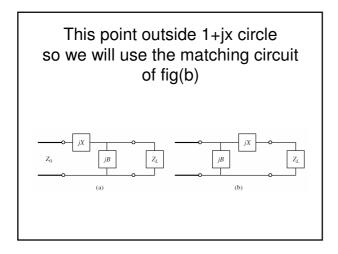
- This matching circuit consist of shunt inductor (*b=-0.7<0*) and a series capacitor (*x=-1.2<0*).
- shunt inductor: $jB=-j/\omega L$ and $B=b/Z_0$ L=-Z₀/2 π fb=-100//2 π 500 \times 10⁶ \times (-0.7)=46.1 nH
- Series capacitor: $jX = -j1/\omega C$ and $X = x.Z_0$ C=-1/ $2\pi f x Z_0 = 2.61 \text{ pF}$

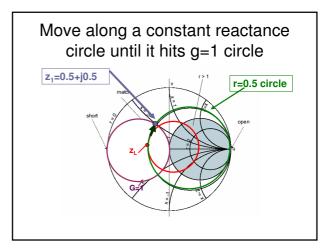
Figure shows the two possible L-section matching circuits and the reflection coefficient magnitude versus frequency for these two matching networks, assuming that the load impedance of Z_L=200j100Ω at 500 MHz consists of a 200Ω resistor and a 3.18 pF capacitor in series. There is no substantial Int of difference in bandwidth for these two solutions.



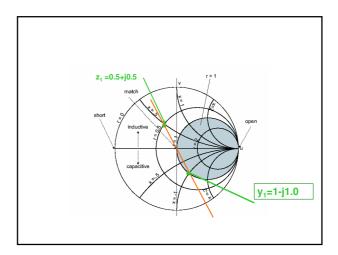








- $z_1 z_L = (0.5 + j0.5) (0.5 + j0.3) = j0.2 = jx$
- Adding a reactance of *jx=j0.2* will move us along a constant reactance circle to *z*₁=0.5+*j*0.5
- After we add the series reactance and convert back to admitance,
- So that we can add a shunt suceptance to cancel the jb and match the load.



- $y_1 = 1 j1.0$, indicating that a shunt suceptance b = j1.0 will bring us to $y = 1(y = 1/Z_0)$.
- This matching circuit consist of shunt capacitor (*b*>0) and a series inductor (*x*>0).

Second solution to this matching problem:

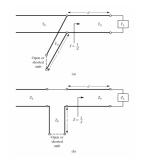
- x₂=-0.8
- b₂=-1

Matching Networks Using TL

•Single-Stub Tuning •Double-Stub Tuning

Single Stub Tuning

• We next consider a matching technique that uses a single open-circuited or short-circuited length of transmission line (a "stub").



· Here, it is important whether we should use

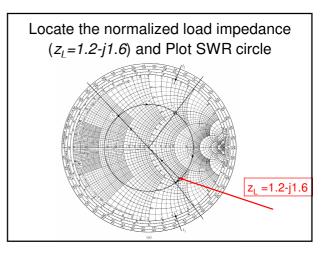
short circuit or

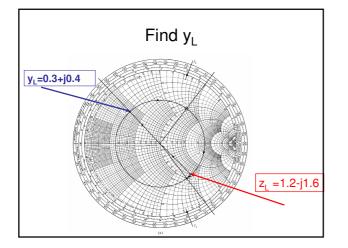
- open circuit stub in the design.
- Due to excessive radiation loss, short circuit stub is preferred if coaxial cable is used.
- On the other hand, for printed circuit board (PCB) design, open-circuit stubs are preferred since they do not require via that is necessary to obtain the ground connection for a short circuit stub.
- Single stub impedance matching is easy to do with the Smith Chart
- Simply find the intersection of the SWR circle with the *r* = 1 circle
- The match is at the center of the circle. Take a reactance in series or shunt to move you there!

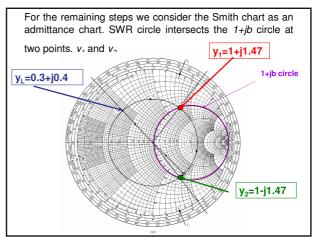
Single-Stub Shunt Tuning

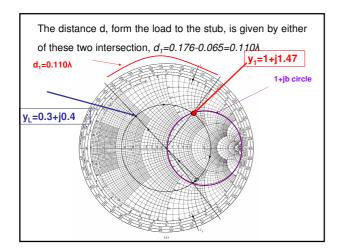
Example:

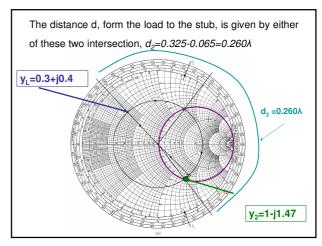
For a load impedance $Z_L=60$ - $j80\Omega$, design two single-stub (short circuit) shunt tuning networks to match this load to a 50Ω line. Assuming that the load is matched at 2 GHz, and that the load consist of a resistor and capacitor in series, Plot the reflection coefficient magnitude from 1 GHz to 3 GHz for each solution





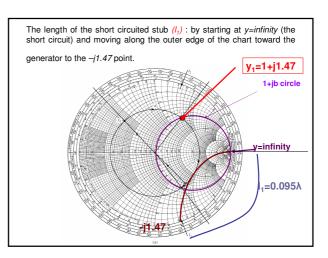


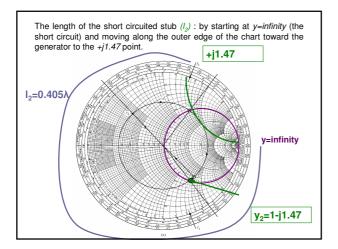


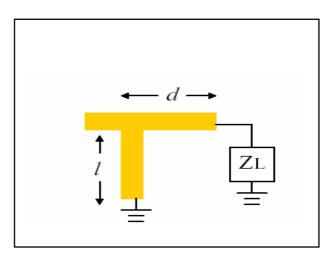


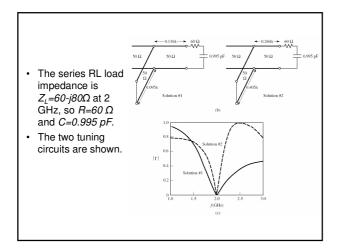
At the two intersection points, the normalized admittances are
y₁=1+j1.47 (a stub with a susceptance -j1.47)

 y_2 =1-j1.47 (a stub with a susceptance +j1.47)



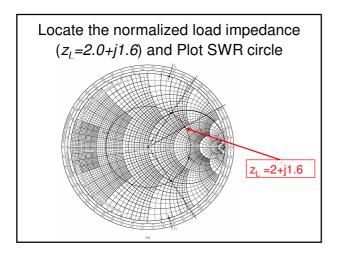


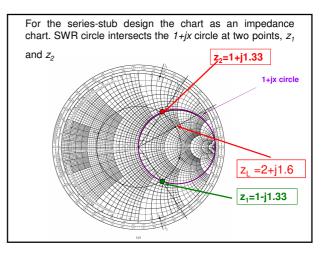


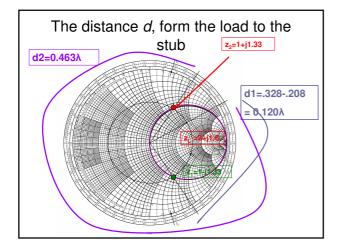


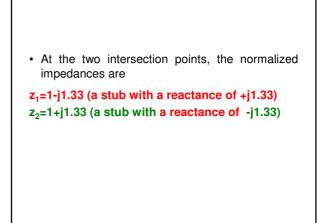
Single-Stub Series Tuning

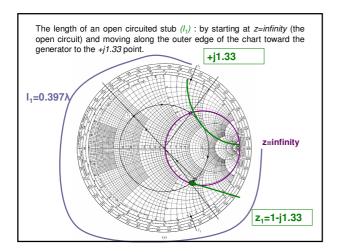
Example: Match a load impedance of $Z_L = 100 + j80$ to a 50Ω line using a single series open-circuit stub. Assuming that the load is matched at 2 GHz, and that the load consist of a resistor an inductor in series, plot the reflection coefficient magnitude from 1 GHz to 3 GHz.

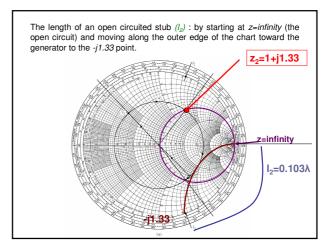


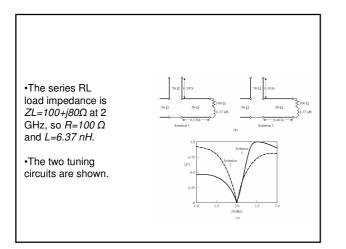






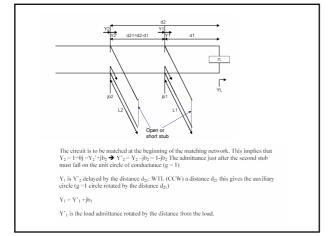






Double-Stub Tuning

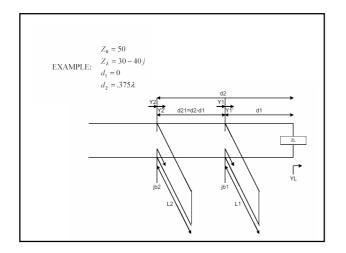
- A single stub must be repositioned to match for different loads. Sometimes this is inconvenient. The double stub method fixes the location of the stubs and varies the lengths. Usually the stubs are separated by standard distances: $\lambda/4$, λ /8, or 3 λ /4.
- The stubs are shunt stubs, which are usually easier to implement in practice than are series stubs.

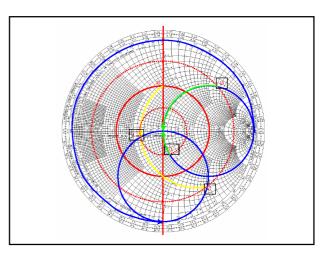


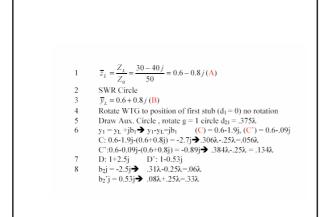
Goal is to get to origin of Smith Chart where r = 1, g = 1, and $\Gamma = 0$

Method:

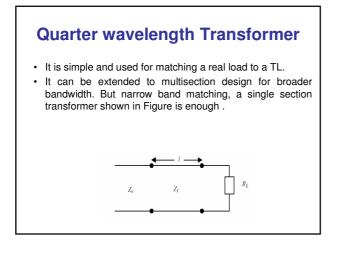
- 1 Normalize load and plot (A)
- 2 Draw SWR circle
- 3 Reflect through origin to get admittance (B)
- 4 Rotate WTG to position of first stub
- 5 Draw Auxiliary Circle by rotating g=1 circle by (CCW)
- 6 Shift to Aux. Circle by adding stub1 (C&C')
- 7 Rotate d21 to second position of second stub (new SWR circle) (D&D')
- 8 Add stub to cancel imaginary part (to origin)







rry mese problems and se	e if you get these answers:
$Z_0 = 50$	$Z_0 = 50$
$Z_L = 60 - 80 j$	$Z_L = 80 + 60j$
$d_1 = 0.1\lambda$	$d_1 = 0.2\lambda$
$d_2 = .225\lambda$	$d_2 = .45\lambda$
$L_1 = .34\lambda$	$L_1 = .172\lambda$
$L_2 = .43\lambda$	$L_2 = .323\lambda$
$L'_{1} = .10\lambda$	$L'_1 = .103\lambda$
$L_2' = .22\lambda$	$L'_2 = .177\lambda$



- The characteristic impedance of the matching section is $Z_{I} = \sqrt{Z_{o}R_{L}}$
- Since the length of the matching section is at the operating frequency, the perfect match cannot be obtained at other frequencies. The reflection coefficient at the input of the transformer can be determined as

$$\Gamma = \frac{R_L - Z_o}{R_L + Z_o + j2 \tan\beta l \sqrt{R_L Z_o}}$$

Near the design frequency the amplitude of the reflection coefficient is reduced to

$$|\Gamma| \cong \frac{|R_L - Z_o|}{2\sqrt{Z_oR_L}} |\cos\theta| \quad \text{for } \theta = \beta l \quad \text{near } \pi/2.$$

Its variation as a function of angle is shown in Figure

The reflection coefficient amplitude for a single section quarter wave transformer near design frequency ($R_L/Z_0=1.2$)

f we set a maximum value for the reflection coefficient, say $\Gamma_{\!\scriptscriptstyle M}$, that can be tolerated, ve can define bandwidth of the transformer as

$$\Delta\theta = 2\left(\frac{\pi}{2} - \theta_m\right)$$

which is shown in Figure 🛛 . The fractional bandwidth is found as

$$\frac{\Delta f}{f_o} = 2 - \frac{4}{\pi} \cos^{-1} \left[\frac{\Gamma_m}{\sqrt{1 - \Gamma_m^2}} \frac{2\sqrt{Z_o R_L}}{R_L - Z_o} \right]$$

It is usually expressed as percentage, $100\Delta f / f_{g}\%$.

Example: Design a single section quarter wave transformer to match a 10Ω load to a 50Ω line at $f_o = 3GHz$. Determine the percentage bandwidth for which the $VSWR \le 1.5$.

